**Preferred Device** 

## **Sidac High Voltage**

## **Bidirectional Triggers**

Bidirectional devices designed for direct interface with the ac power line. Upon reaching the breakover voltage in each direction, the device switches from a blocking state to a low voltage on—state. Conduction will continue like a Triac until the main terminal current drops below the holding current. The plastic axial lead package provides high pulse current capability at low cost. Glass passivation insures reliable operation. Applications are:

- High Pressure Sodium Vapor Lighting
- Strobes and Flashers
- Ignitors
- High Voltage Regulators
- Pulse Generators
- Used to Trigger Gates of SCR's and Triacs
- **%** Indicates UL Registered File #E116110
- Device Marking: Logo, Device Type, e.g., MKP3V120, Date Code

#### **MAXIMUM RATINGS** (T<sub>J</sub> = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Repetitive Off–State Voltage (Sine Wave, 50 to 60 Hz, T <sub>J</sub> = -40 to 125°C)  MKP3V120 MKP3V240	V <sub>DRM</sub> , V <sub>RRM</sub>	±90 ±180	Volts
On-State RMS Current (T <sub>L</sub> = 80°C, Lead Length = 3/8", All Conduction Angles)	IT(RMS)	±1.0	Amp
Peak Non–Repetitive Surge Current (60 Hz One Cycle Sine Wave, Peak Value, T <sub>J</sub> = 125°C)	ITSM	±20	Amps
Operating Junction Temperature Range	TJ	-40 to +125	°C
Storage Temperature Range	T <sub>stg</sub>	-40 to +150	°C



#### ON Semiconductor

http://onsemi.com

# SIDACS (%) 1 AMPERE RMS 120 and 240 VOLTS





#### **ORDERING INFORMATION**

Device	Package	Shipping
MKP3V120	SURMETIC 50	Bulk 500/Bag
MKP3V120RL	SURMETIC 50	Tape and Reel 1.5K/Reel
MKP3V240	SURMETIC 50	Bulk 500/Bag
MKP3V240RL	SURMETIC 50	Tape and Reel 1.5K/Reel

**Preferred** devices are recommended choices for future use and best overall value.

#### THERMAL CHARACTERISTICS

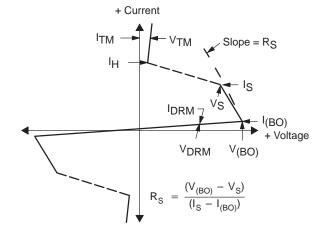
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Lead (Lead Length = 3/8")	$R_{\theta JL}$	15	°C/W
Lead Solder Temperature (Lead Length ≥ 1/16" from Case, 10 s Max)	TL	260	°C

#### **ELECTRICAL CHARACTERISTICS** (T<sub>C</sub> = 25°C unless otherwise noted; Electricals apply in both directions)

Characteristic		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS		•	•			
Repetitive Peak Off–State Current (50 to 60 Hz Sine Wave) VDRM = 90 V VDRM = 180 V ON CHARACTERISTICS	MKP3V120 MKP3V240	<sup>I</sup> DRM	_	_	10	μА
Breakover Voltage, I <sub>BO</sub> = 200 μA	MKP3V120 MKP3V240	V <sub>BO</sub>	110 220		130 250	Volts
Breakover Current		I <sub>BO</sub>	_		200	μΑ
Peak On–State Voltage (I <sub>TM</sub> = 1 A Peak, Pulse Width ≤ 300 μs, Du	uty Cycle ≤ 2%)	VTM	-	1.1	1.5	Volts
Dynamic Holding Current (Sine Wave, 60 Hz, $R_L = 100 \Omega$ )		lН	_	_	100	mA
Switching Resistance (Sine Wave, 50 to 60 Hz)		RS	0.1	_	_	kΩ
DYNAMIC CHARACTERISTICS			•			
Critical Rate–of–Rise of On–State Current, Critical Damped Waveform Circuit (I <sub>PK</sub> = 130 Amps, Pulse Width = 10 μsec)		di/dt	_	120	_	A/μs

## Voltage Current Characteristic of SIDAC (Bidirectional Device)

	<del>,</del>
Symbol	Parameter
I <sub>DRM</sub>	Off State Leakage Current
VDRM	Off State Repetitive Blocking Voltage
V <sub>BO</sub>	Breakover Voltage
IBO	Breakover Current
lΗ	Holding Current
V <sub>TM</sub>	On State Voltage
I <sub>TM</sub>	Peak on State Current



#### **CURRENT DERATING**

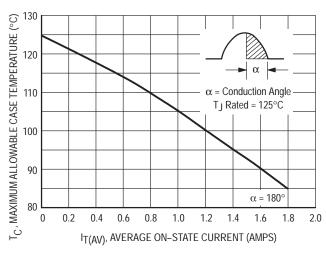


Figure 1. Maximum Case Temperature

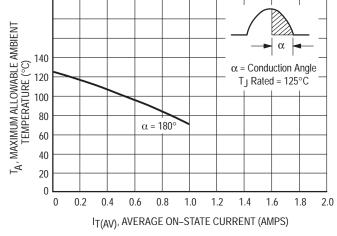


Figure 2. Maximum Ambient Temperature

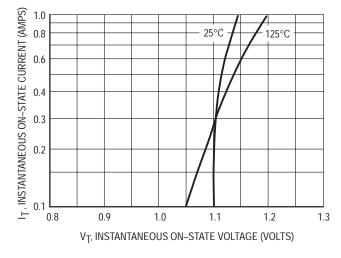
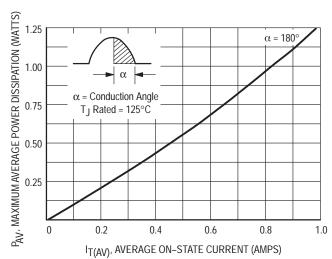


Figure 3. Typical Forward Voltage



**Figure 4. Typical Power Dissipation** 

#### THERMAL CHARACTERISTICS

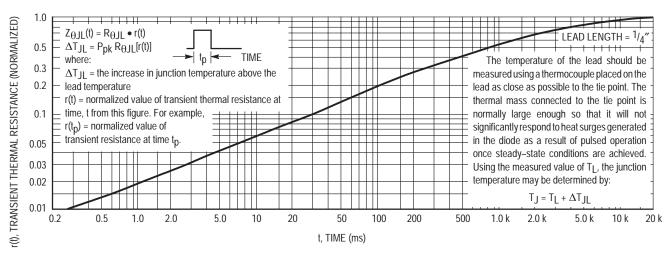


Figure 5. Thermal Response

#### **TYPICAL CHARACTERISTICS**

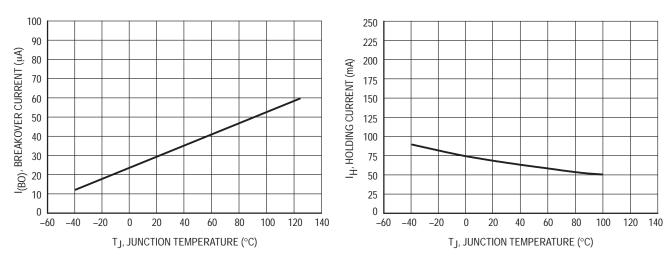


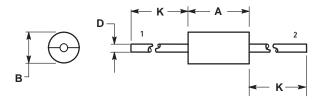
Figure 6. Typical Breakover Current

**Figure 7. Typical Holding Current** 

#### **PACKAGE DIMENSIONS**

#### **SURMETIC 50**

PLASTIC AXIAL (No Polarity) CASE 267-03 ISSUE D



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.370	0.380	9.40	9.65
В	0.190	0.210	4.83	5.33
D	0.048	0.052	1.22	1.32
K	1.000		25.40	

STYLE 2: NO POLARITY





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